# VS-VSKJS440/030

**Vishay Semiconductors** 





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AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub> 440 A				
V <sub>R</sub>	30 V			
Package	AAP Gen 7 (TO-240AA)			
Circuit configuration	Two diodes common anode			

### **MECHANICAL DESCRIPTION**

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Low forward voltage drop
- High frequency operation
- · Low thermal resistance



- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### BENEFITS

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

### **ELECTRICAL DESCRIPTION / APPLICATIONS**

The VS-VSKJS440/030 Schottky rectifier common anode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	440	А	
V <sub>RRM</sub>		30	V	
I <sub>FSM</sub>	$t_p = 5 \ \mu s \ sine$	27 000	А	
V <sub>F</sub>	200 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.61	V	
Тј	Range	-55 to +150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-VSKJS440/030	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	30	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	30	v	



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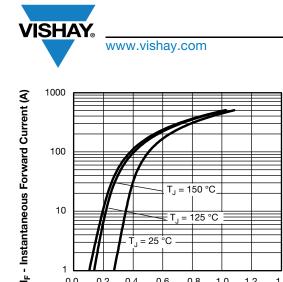
ABSOLUTE MAXIMUM RATINGS						
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS		VALUES	UNITS		
Maximum average	per module		50 % duty cycle at $T_{C}$ = 97 °C, rectangular waveform		440	
forward current	per leg	I <sub>F(AV)</sub>			220	
Maximum peak one cycle			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	27 000	A
non-repetitive surge current		IFSM	10 ms sine or 6 ms rect. pulse	rated $V_{RRM}$ applied	3000	
Non-repetitive avalanche energ	у	E <sub>AS</sub>	E <sub>AS</sub> T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 20 A, L = 1 mH		198	mJ
Repetitive avalanche current		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		А	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V <sub>FM</sub>	220 A	T <sub>J</sub> = 25 °C	0.68	v
Maximum forward voltage drop		440 A		1.0	
Maximum forward voltage drop		220 A	T <sub>J</sub> = 125 °C	0.61	
		440 A		0.93	
Martin and the last second	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	20	mA
Maximum reverse leakage current		T <sub>J</sub> = 125 °C		1120	ma
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		14 800	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.26	°C/W	
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>		0.1		
Approvimate weight				75	g	
Approximate weight				2.7	oz.	
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the		Nm	
	busbar		spread of the compound.	3		
Case style			JEDEC®	TO-240AA co	mpatible	

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= 25 ċС

0.6

0.8

V<sub>FM</sub> - Forward Voltage Drop (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics

1.0

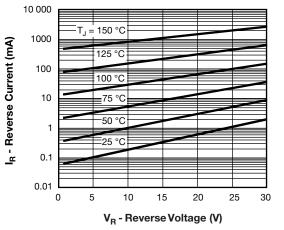
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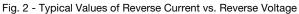
1.4

0.4

0.0

0.2





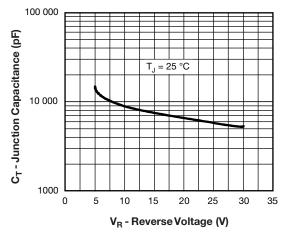


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

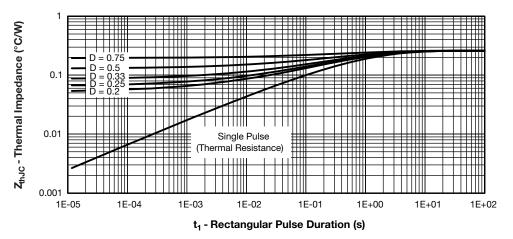


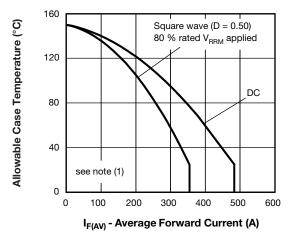
Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

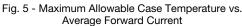
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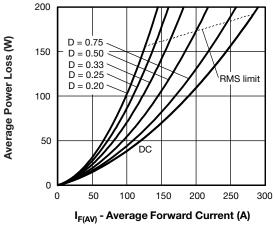


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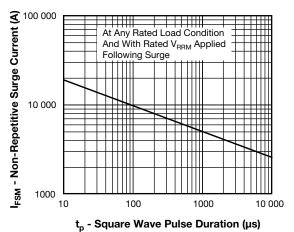


Fig. 7 - Maximum Non-Repetitive Surge Current

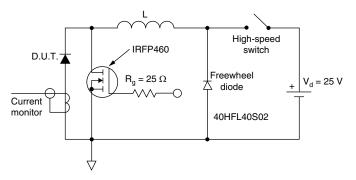


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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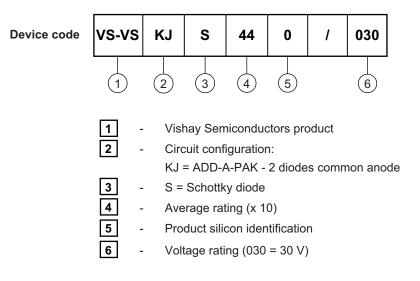
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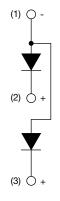
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### **ORDERING INFORMATION TABLE**



### **CIRCUIT CONFIGURATION**



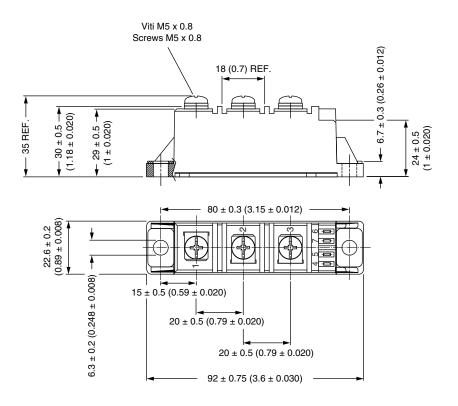
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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## **ADD-A-PAK Generation VII - Diode**

### **DIMENSIONS** in millimeters (inches)





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